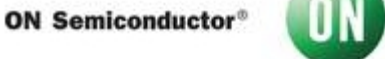




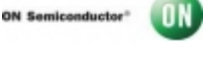
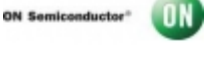
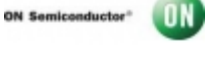
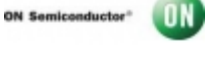
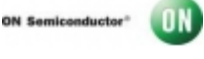
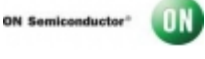
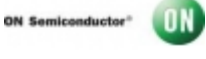
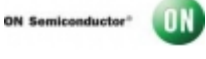
|  |   |
|--|---|
|   | <h2 style="color: red;">NGTD30T120F2WP</h2>   |
| <br><small>Not Actual Photo<br/>YIC International Co., Limited.</small> | <p><b>Hersteller-Teilenummer:</b> <a href="#">NGTD30T120F2WP</a></p> <hr/> <p><b>Hersteller / Marke:</b> <a href="#">AMI Semiconductor / ON Semiconductor</a></p> <hr/> <p><b>Teil der Beschreibung:</b> IGBT TRENCH FIELD STOP 1200V DIE</p> <hr/> <p><b>Datenblätter:</b>  <a href="#">NGTD30T120F2WP.pdf</a></p> <hr/> <p><b>RoHS Status:</b> Bleifrei / RoHS-konform</p> <hr/> <p><b>Lagerzustand:</b> New original, Stock Available.</p> <hr/> <p><b>Liefern von:</b> Hong Kong</p> <hr/> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p> |
| <p>Image may be representation.<br/>See specs for product details.</p>   |   |

### Spezifikationen

|   |   |
|---|---|
| Teilenummer                                   | <a href="#">NGTD30T120F2WP</a>  |
| Hersteller                                    | <a href="#">AMI Semiconductor / ON Semiconductor</a>                                    |
| Beschreibung                                  | IGBT TRENCH FIELD STOP 1200V DIE  |
| Kategorie                                     | <a href="#">Diskrete Halbleiterprodukte</a> > <a href="#">Transistoren-IGBTs-Einzel</a> |
| Teilstatus                                    | <a href="#">Require For Quote &amp; Check Stock</a>                                     |
| Spannung - Kollektor-Emitter-Durchbruch (max) | 1200V   |
| VCE (on) (Max) @ Vge, Ic                      | 2.4V @ 15V, 40A   |
| Testbedingung                                 | -   |
| Td (ein / aus) bei 25 ° C                     | -   |
| Schaltenergie                                 | -   |
| Supplier Device-Gehäuse                       | Die   |
| Serie   | -   |
| Verpackung                                    | Bulk  |
| Verpackung / Gehäuse                          | Die   |
| Betriebstemperatur                            | -55°C ~ 175°C (TJ)  |
| Befestigungsart                               | Surface Mount   |
| Hersteller Standard Vorlaufzeit               | 21 Weeks  |
| Bleifreier Status / RoHS-Status               | Lead free / RoHS Compliant  |
| Eingabetyp                                    | Standard  |
| IGBT-Typ                                      | Trench Field Stop   |
| detaillierte Beschreibung                     | IGBT Trench Field Stop 1200V Surface Mount Die  |
| Strom - Collector Pulsed (Icm)                | 200A  |

NGTD30T120F2WP Electronic Components ist ein 100% neues Original von YIC Distributor, NGTD30T120F2WP-Datenblätter durchsuchen, PDF, Inventar bei Y-IC.com Online, NGTD30T120F2WP AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen bestellen. Versand per DHL / FedEx / TNT / UPS Express. Unterstützung der Zahlung mit telegrafischer Überweisung (T / T) oder PayPal.  
RFQ NGTD30T120F2WP E-Mail: [Info@Y-IC.com](mailto:Info@Y-IC.com)

### Sie können auch interessiert

|   |   |   |   |
|---|---|---|---|
| <p>sein:</p>  <p><b>NGTD5R65F2SWK</b><br/>AMI Semiconductor / ON Semiconductor<br/>DIODE GEN PURP 650V DIE</p> |  <p><b>NGTD28T65F2SWK</b><br/>AMI Semiconductor / ON Semiconductor<br/>IGBT TRENCH FIELD STOP 650V DIE</p>   |  <p><b>NGTD8R65F2SWK</b><br/>AMI Semiconductor / ON Semiconductor<br/>DIODE GEN PURP 650V DIE</p> |  <p><b>NGTD30T120F2SWK</b><br/>AMI Semiconductor / ON Semiconductor<br/>IGBT TRENCH FIELD STOP 1200V DIE</p> |
|  <p><b>NGTD28T65F2WP</b><br/>AMI Semiconductor / ON Semiconductor<br/>IGBT TRENCH FIELD STOP 650V DIE</p>      |  <p><b>NGTD23T120F2SWK</b><br/>AMI Semiconductor / ON Semiconductor<br/>IGBT TRENCH FIELD STOP 1200V DIE</p> |  <p><b>NGTD8R65F2WP</b><br/>AMI Semiconductor / ON Semiconductor<br/>DIODE GEN PURP 650V DIE</p>  |  <p><b>NGTD5R65F2WP</b><br/>AMI Semiconductor / ON Semiconductor<br/>DIODE GEN PURP 650V DIE</p>             |

### Verwandtes Hot-Keyword

Mehr

|   |  |   |                                      |   |
|---|--|---|--------------------------------------|---|
| <a href="#">NGTD30T120F2WP AMI Semiconductor / ON Semiconductor</a> | <a href="#">NGTD30T120F2WP Datenblatt</a>  | <a href="#">NGTD30T120F2WP-Datenblätter</a> | <a href="#">NGTD30T120F2WP PDF</a>   | <a href="#">AMI Semiconductor / ON Semiconductor NGTD30T120F2WP</a> |
| <a href="#">NGTD30T120F2WP Electronic</a>                           | <a href="#">NGTD30T120F2WP-Komponenten</a> | <a href="#">NGTD30T120F2WP-Verteiler</a>    | <a href="#">NGTD30T120F2WP-Bild</a>  | <a href="#">NGTD30T120F2WP-Teil</a>                                 |
| <a href="#">NGTD30T120F2WP Preis</a>                                | <a href="#">NGTD30T120F2WP Hersteller</a>  | <a href="#">NGTD30T120F2WP Bild</a>         | <a href="#">NGTD30T120F2WP Aktie</a> | <a href="#">NGTD30T120F2WP Inventar</a>                             |
| <a href="#">NGTD30T120F2WP Neu</a>                                  | <a href="#">NGTD30T120F2WP Original</a>    | <a href="#">NGTD30T120F2WP garantiert</a>   | <a href="#">NGTD30T120F2WP RFQ</a>   | <a href="#">NGTD30T120F2WP Online bestellen</a>                     |

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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